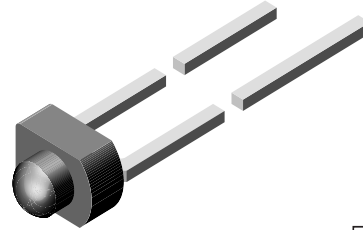


## Universal LED, $\varnothing$ 1.8 mm Tinted Diffused Miniplast Package

### Features

- For DC and pulse operation
- Luminous intensity categorized
- End-to-end stackable in centre-to-centre spacing of 0.1" (2.54 mm)
- Lead-free device



19229



### Applications

General indicating and lighting purposes

### Parts Table

Part	Color, Luminous Intensity	Angle of Half Intensity ( $\pm\phi$ )	Technology
TLUR2400	Red, $I_V > 15$ mcd (typ.)	20 °	GaAsP on GaP
TLUR2401	Red, $I_V = (4 \text{ to } 32)$ mcd	20 °	GaAsP on GaP

### Absolute Maximum Ratings

$T_{amb} = 25$  °C, unless otherwise specified

#### TLUR240.

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		$V_R$	6	V
DC Forward current		$I_F$	20	mA
Surge forward current	$t_p \leq 10$ $\mu$ s	$I_{FSM}$	0.5	A
Power dissipation	$T_{amb} \leq 55$ °C	$P_V$	60	mW
Junction temperature		$T_j$	100	°C
Operating temperature range		$T_{amb}$	- 40 to + 100	°C
Storage temperature range		$T_{stg}$	- 55 to + 100	°C
Soldering temperature	$t \leq 3$ s, 2 mm from body	$T_{sd}$	260	°C
	$t \leq 5$ s, 4 mm from body	$T_{sd}$	260	°C
Thermal resistance junction/ambient		$R_{thJA}$	450	K/W

### Optical and Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

#### Red

#### TLUR240.

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity <sup>1)</sup>	$I_F = 10\text{ mA}$	TLUR2400	$I_V$	4	15		mcd
		TLUR2401	$I_V$	4		32	mcd
Dominant wavelength	$I_F = 10\text{ mA}$		$\lambda_d$		630		nm
Peak wavelength	$I_F = 10\text{ mA}$		$\lambda_p$		640		nm
Angle of half intensity	$I_F = 10\text{ mA}$		$\phi$		$\pm 20$		deg
Forward voltage	$I_F = 20\text{ mA}$		$V_F$		2	3	V
Reverse voltage	$I_R = 10\text{ }\mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1\text{ MHz}$		$C_j$		50		pF

<sup>1)</sup> in one Packing Unit  $I_{Vmin}/I_{Vmax} \leq 0.5$

### Typical Characteristics ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

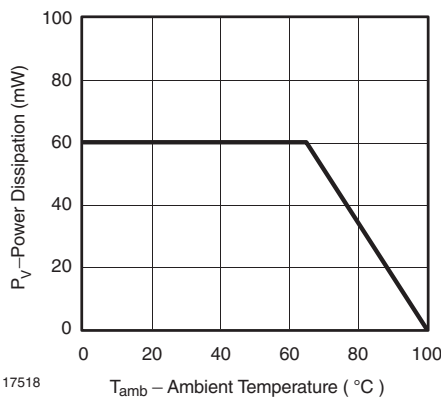


Figure 1. Power Dissipation vs. Ambient Temperature

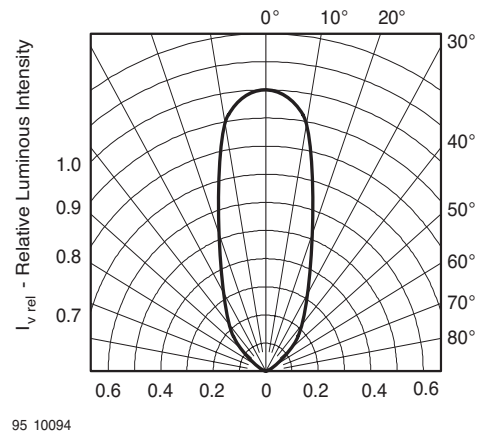


Figure 3. Rel. Luminous Intensity vs. Angular Displacement

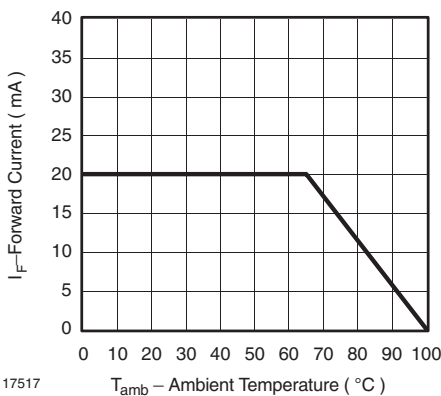


Figure 2. Forward Current vs. Ambient Temperature

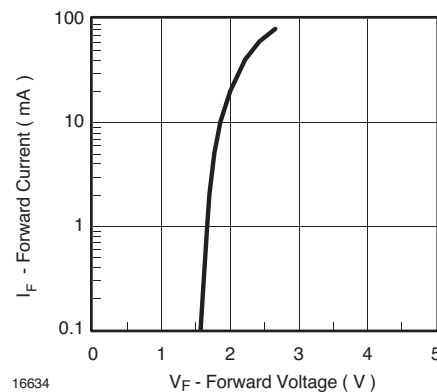


Figure 4. Forward Current vs. Forward Voltage

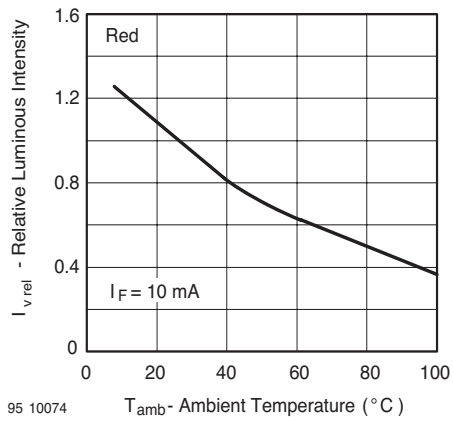


Figure 5. Rel. Luminous Intensity vs. Ambient Temperature

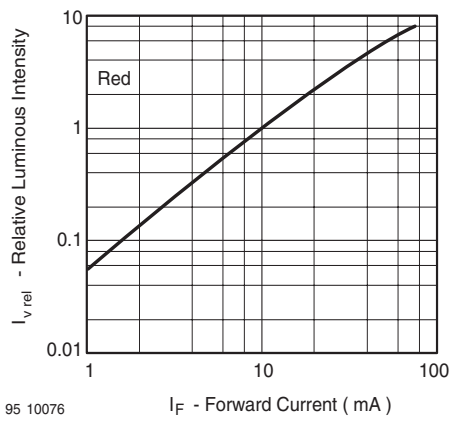


Figure 6. Relative Luminous Intensity vs. Forward Current

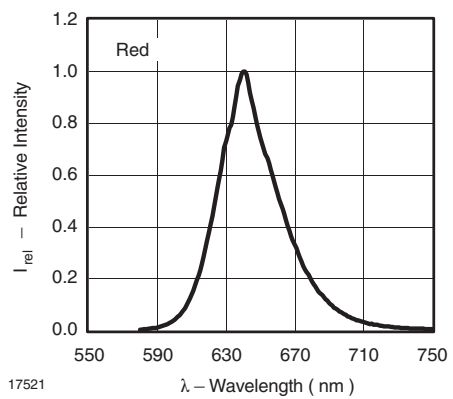
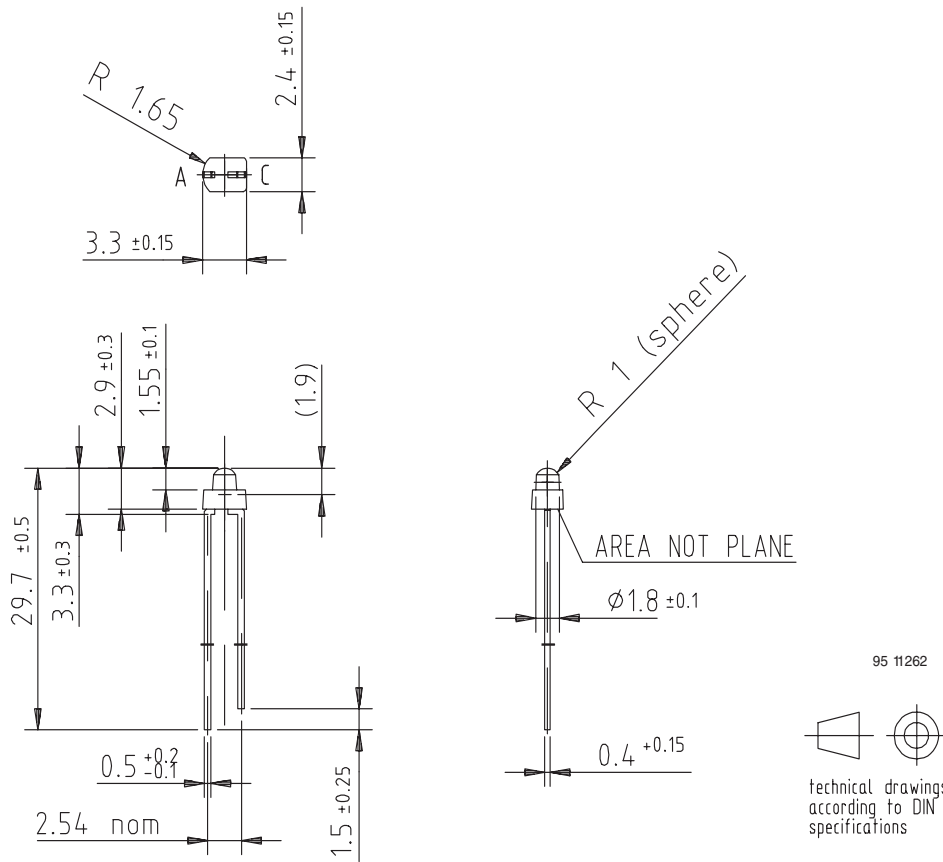


Figure 7. Relative Intensity vs. Wavelength

## Package Dimensions in mm



## **Ozone Depleting Substances Policy Statement**

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**Vishay Semiconductor GmbH** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design  
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